Schottky Rectifier, 3 A

SMC

FEATURES

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

Available
RoHS* COMPLIANT

DESCRIPTION

The 30BQ100GPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	3.0 A
V_R	100 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	3.0	A
V_{RRM}		100	V
I_{FSM}	t_p = 5 µs sine	800	A
V_F	3.0 Apk, T_J = 125 °C	0.62	V
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	30BQ100GPbF	UNITS
Maximum DC reverse voltage	V_R	100	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at T_L = 148 °C, rectangular waveform		3.0	A
		50 % duty cycle at T_L = 138 °C, rectangular waveform		4.0	
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	800	
		10 ms sine or 6 ms rect. pulse		70	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 1.0 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.5	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM} (1)	3 A	T_J = 25 °C	0.79	V
		6 A		0.90	
		3 A	T_J = 125 °C	0.62	
		6 A		0.70	
Maximum reverse leakage current	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	0.1	mA
		T_J = 125 °C		5.0	
Maximum junction capacitance	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		115	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		3.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg} (1)		- 55 to 175	°C
Maximum thermal resistance, junction to lead	R_{thJL} (2)	DC operation	12	°C/W
Maximum thermal resistance, junction to ambient	R_{thJA}		46	
Approximate weight			0.24	g
			0.008	oz.
Marking device		Case style SMC (similar to DO-214AB)	V3JG	

Notes

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

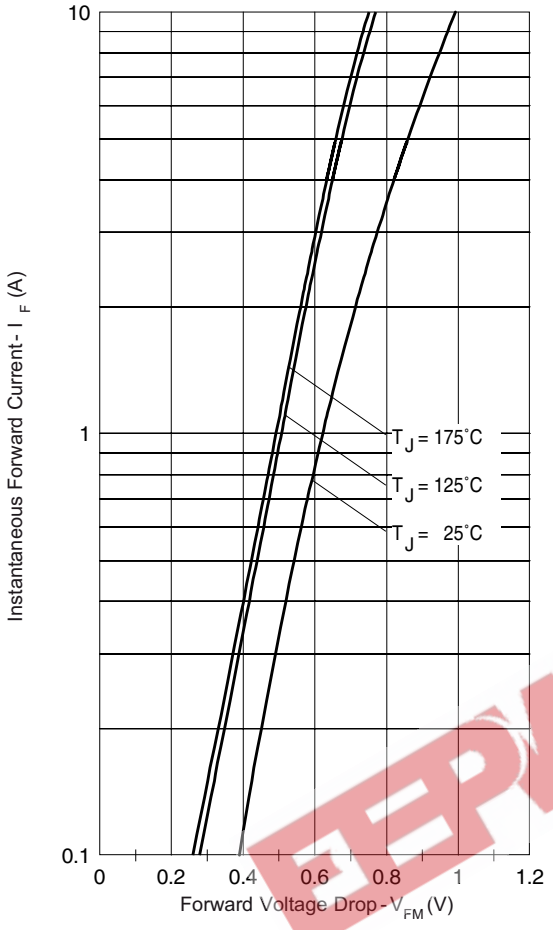


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

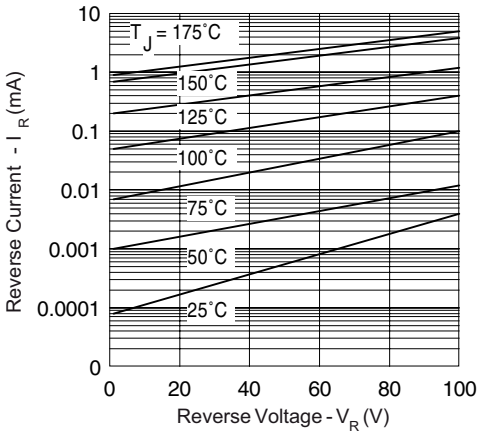


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

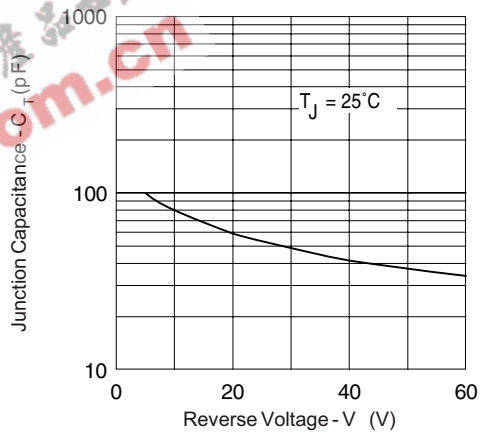


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

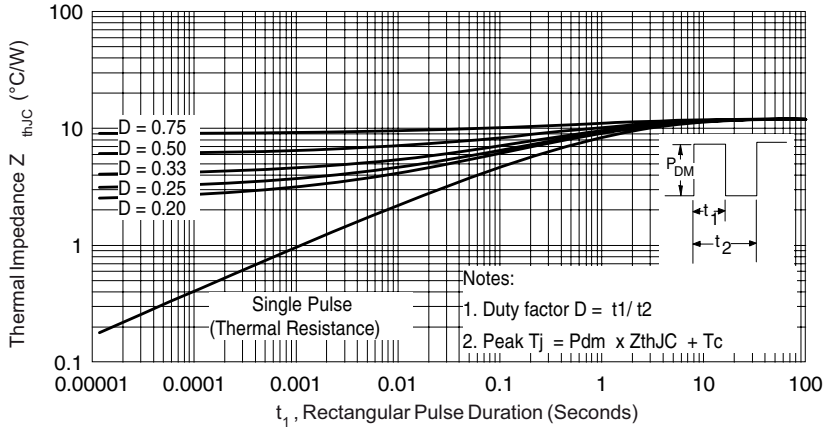


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

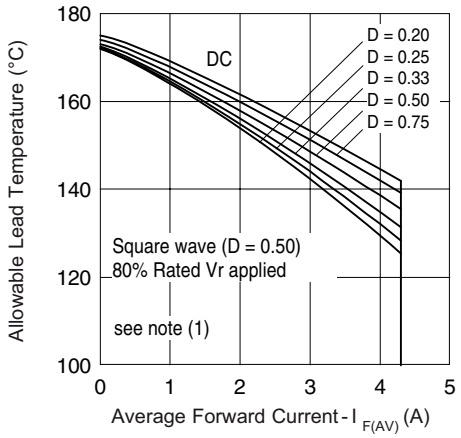


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

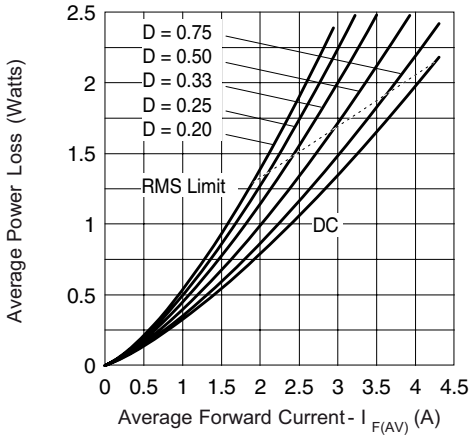


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

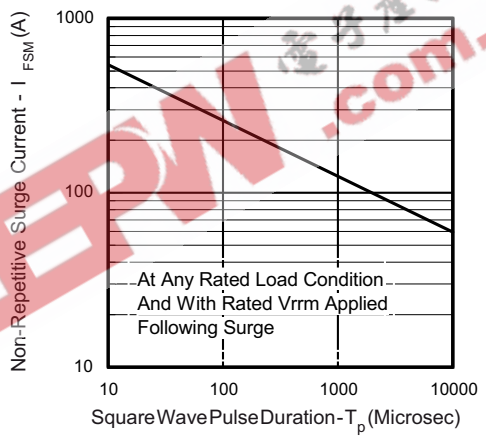


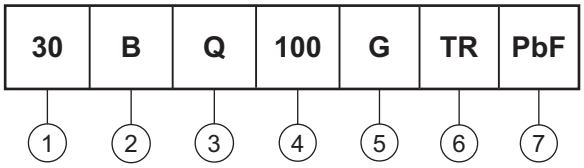
Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R(1 - D)$; I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code



1	-	Current rating
2	-	B = Single lead diode
3	-	Q = Schottky Q series
4	-	Voltage rating (100 = 100 V)
5	-	G = Schottky generation
6	-	• None = Box (1000 pieces) • TR = Tape and reel (3000 pieces)
7	-	• None = Standard production • PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95023
Part marking information	http://www.vishay.com/doc?95029
Packaging information	http://www.vishay.com/doc?95034

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